

Coulomb Shift of the Intersubband Resonance and Temperature Bistability of Electrons on He

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May 22, 2010, Princeton

Outline

- Introduction

- Experiment

- Results

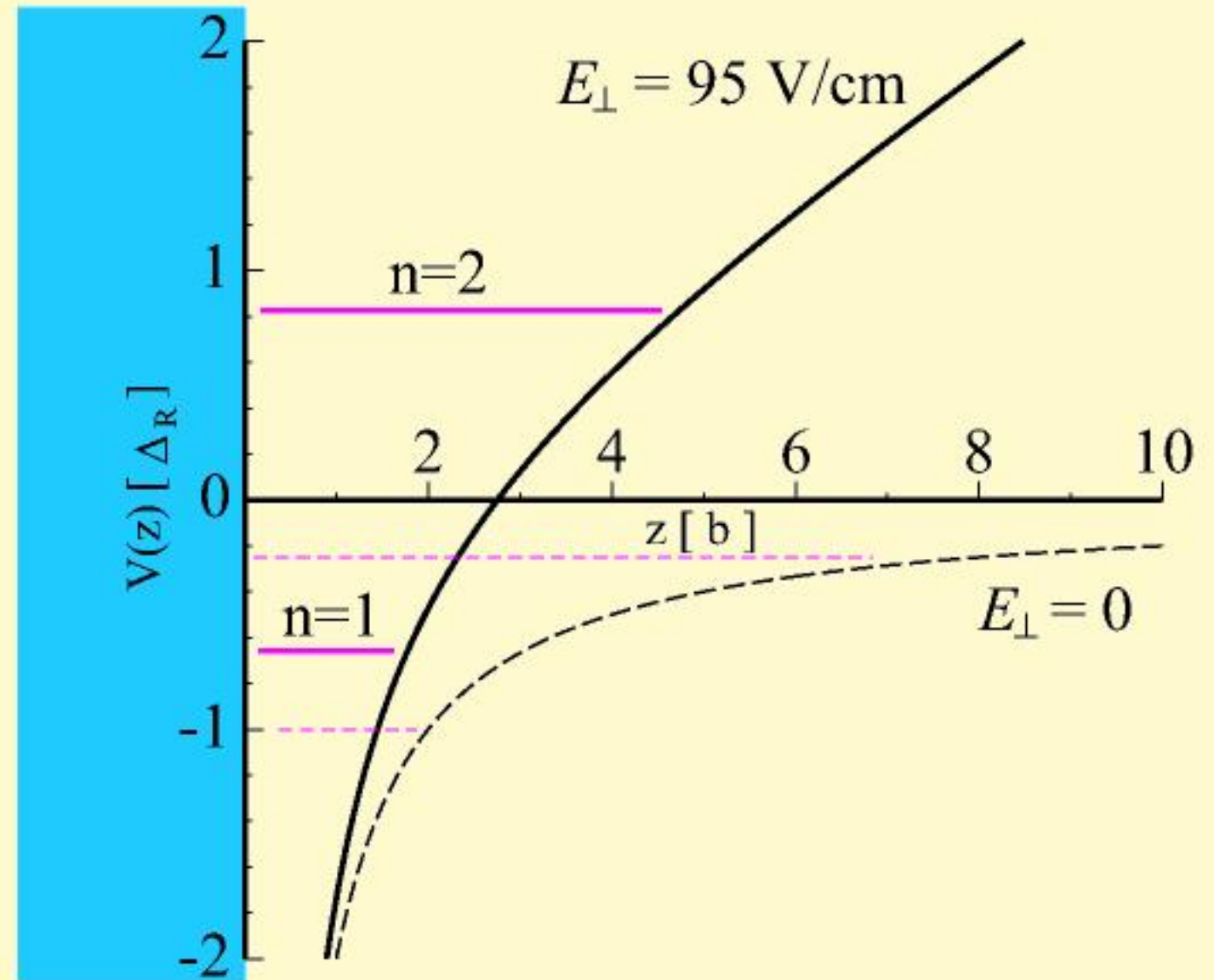
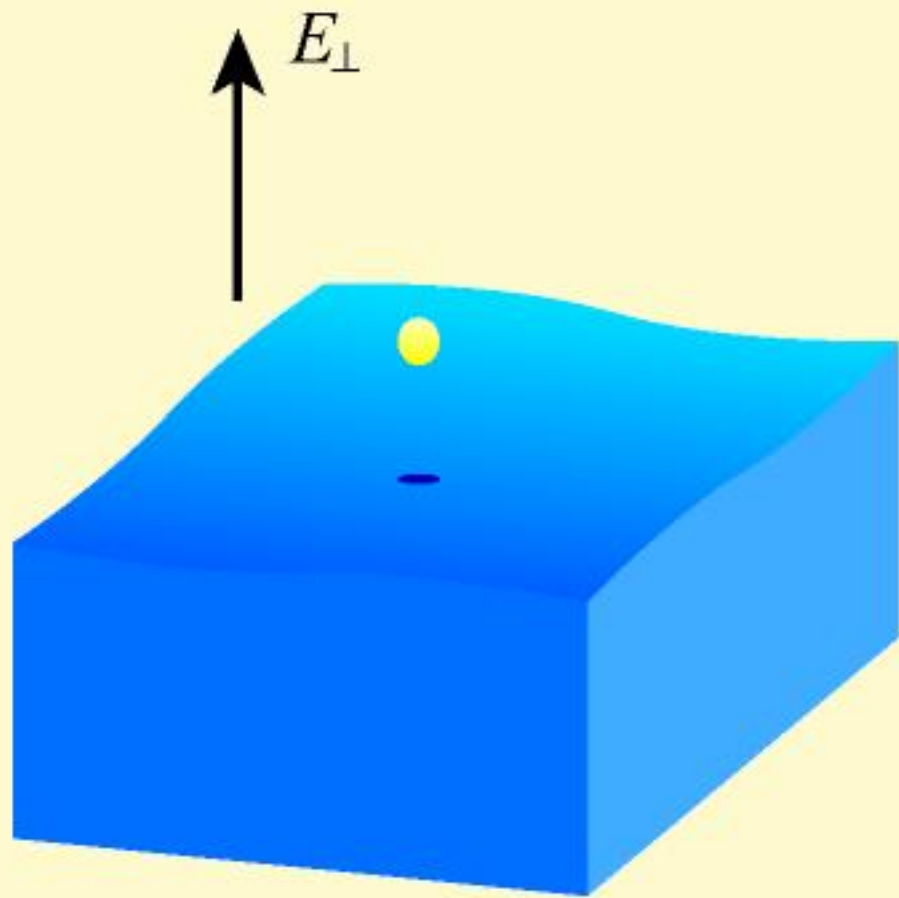
- Microwave (MW) absorption induced hot-electron effect
- Frequency shift due to Coulomb interaction
- Bistability

- Summary

D. Konstantinov et al.: Phys. Rev. Lett. 98, 235302 (2007).

D. Konstantinov et al.: Phys. Rev. Lett. 103, 096801 (2009).

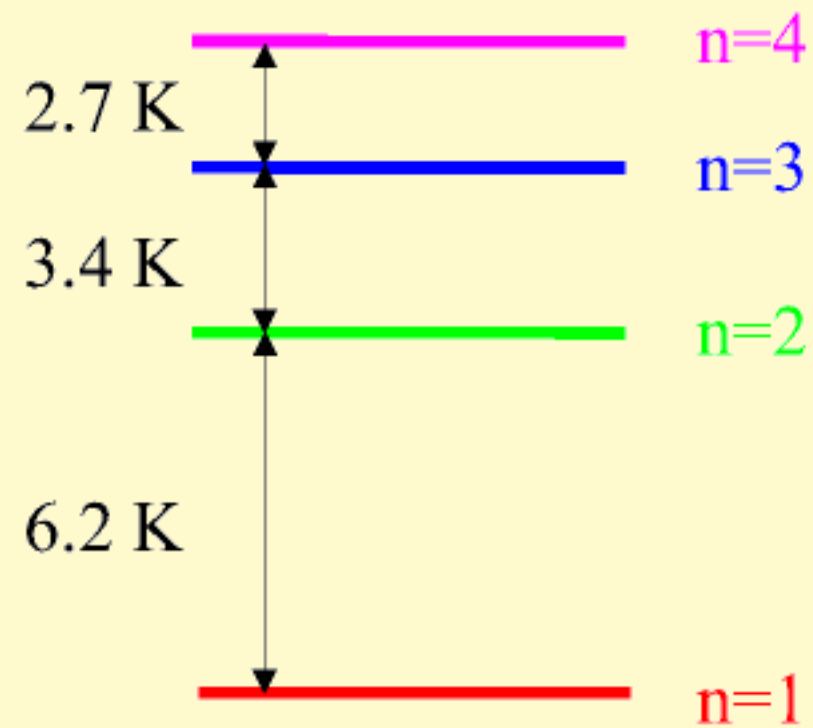
Surface states



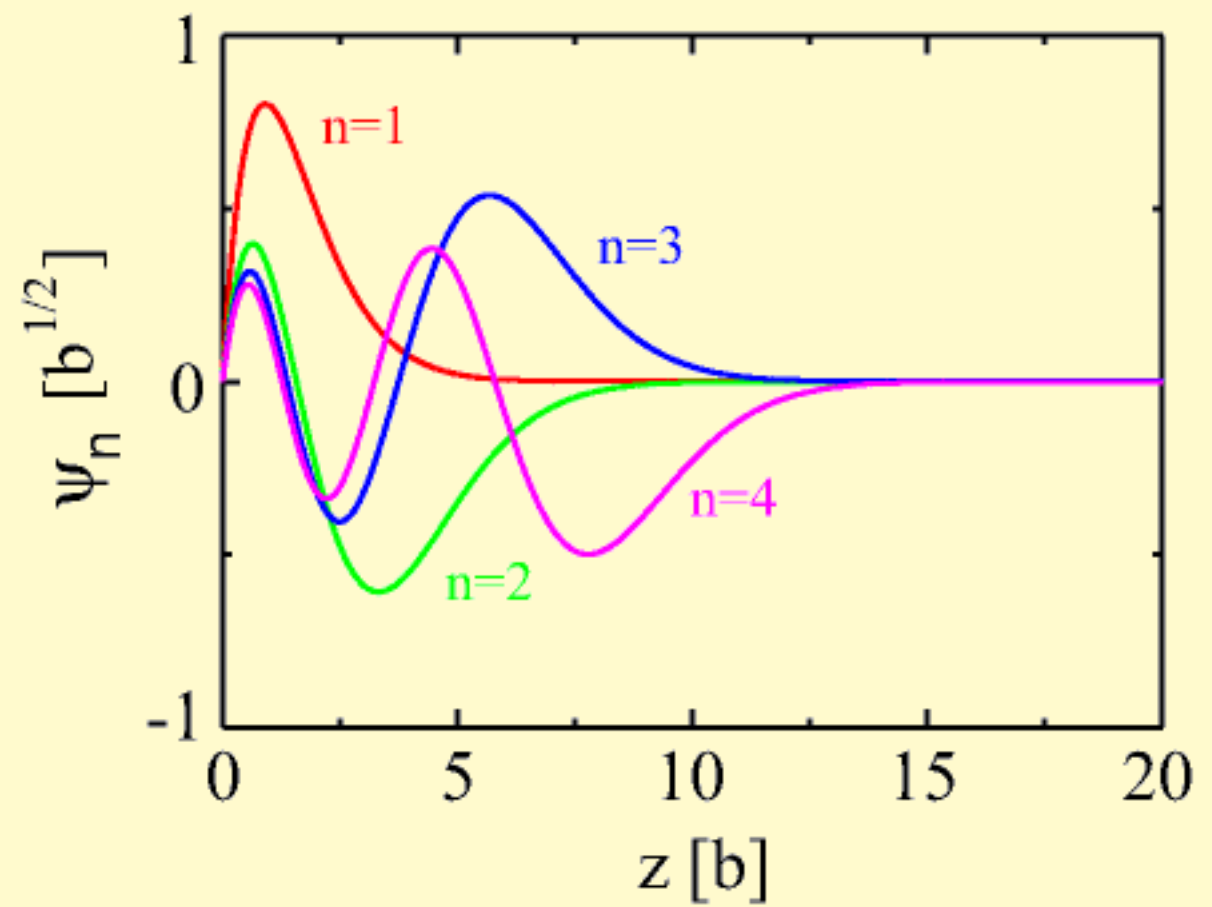
$$V(z) = -\frac{\Lambda e^2}{z} + eE_{\perp}z$$

Wave functions

$$\left[-\frac{\hbar^2}{2m} \frac{\partial^2}{\partial z^2} - \frac{\Lambda e^2}{z} + eE_{\perp} z \right] \psi_n(z) = \epsilon_n \psi_n(z)$$



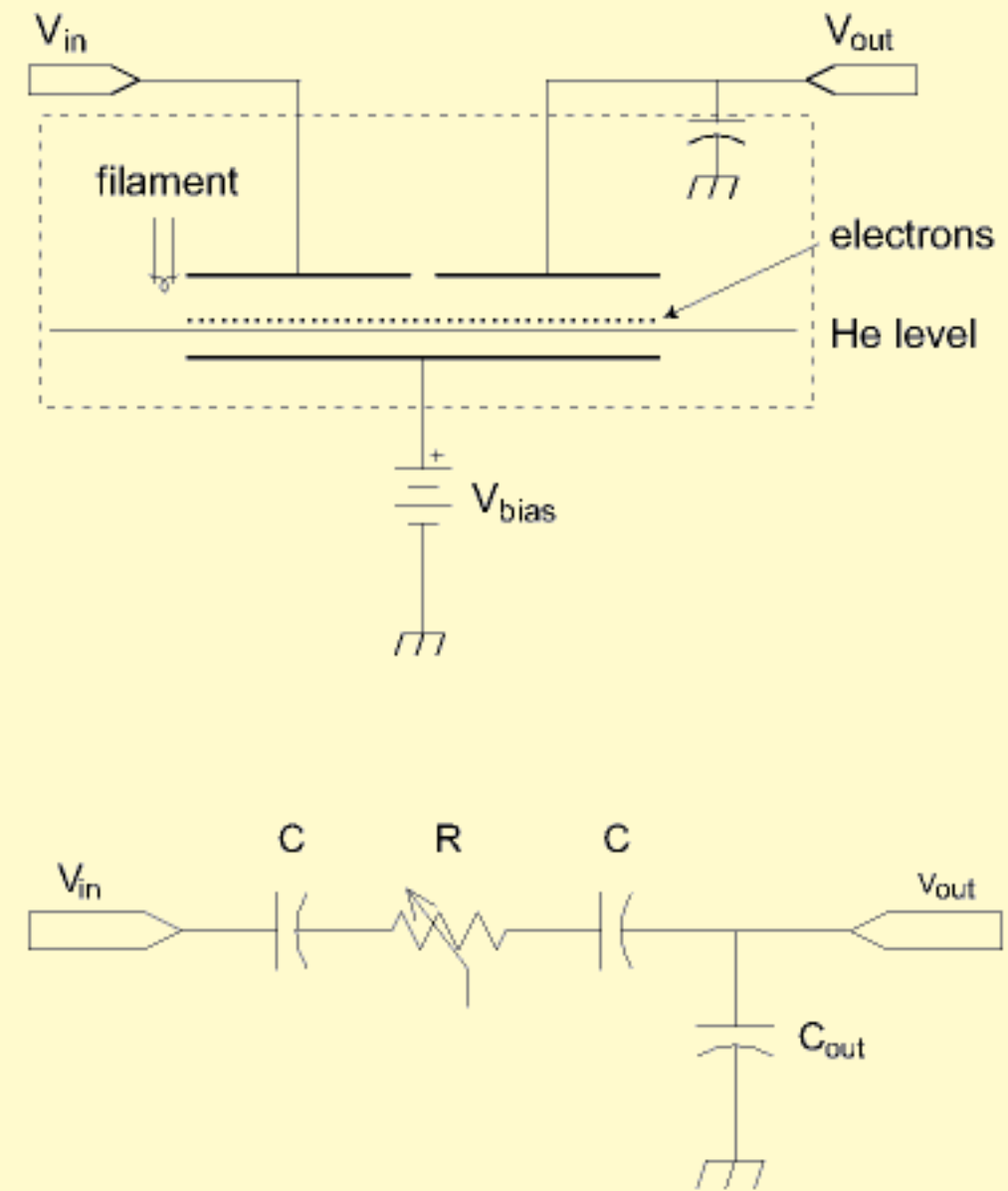
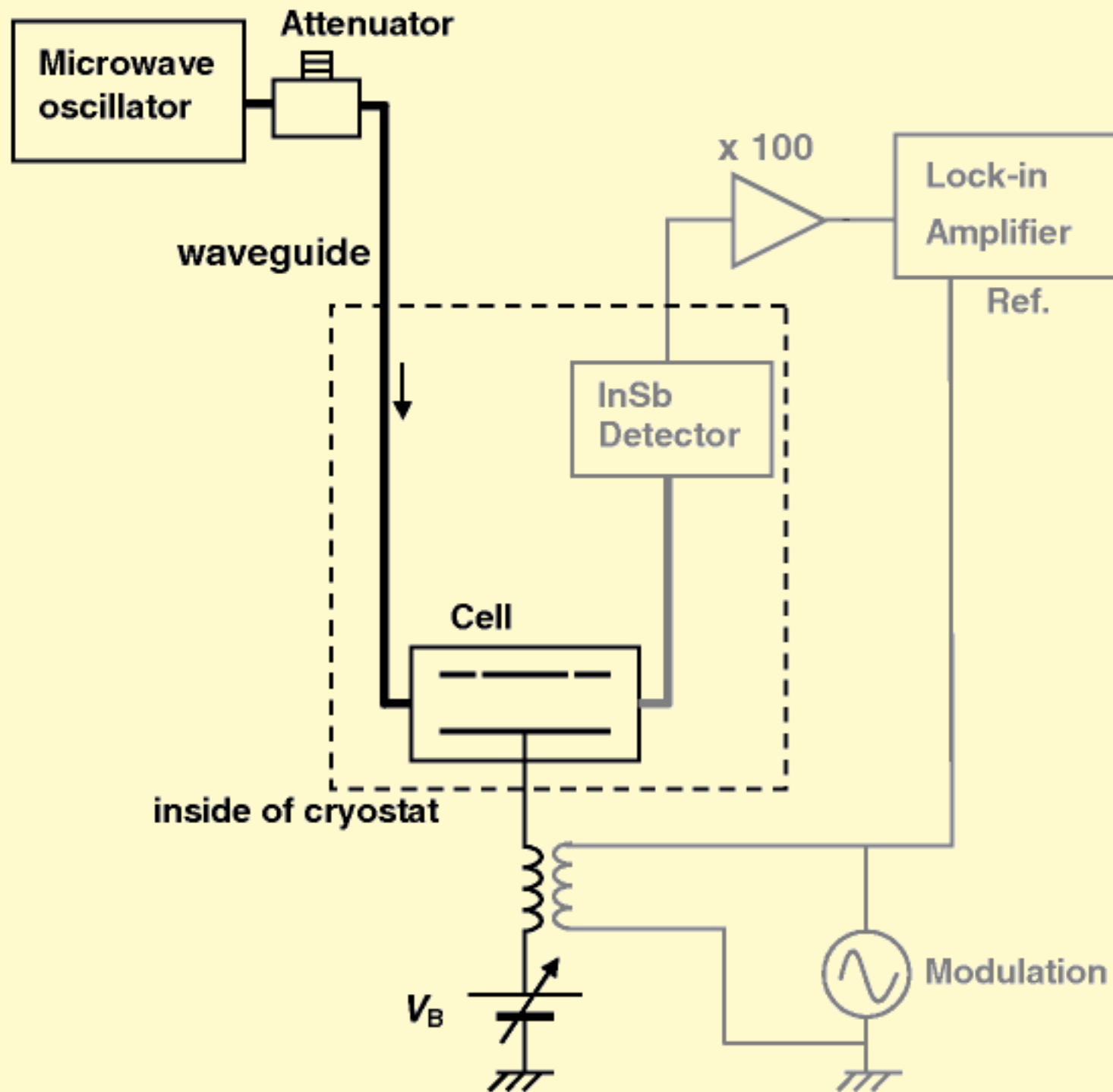
$E_{\perp} = 95 \text{ V/cm}$



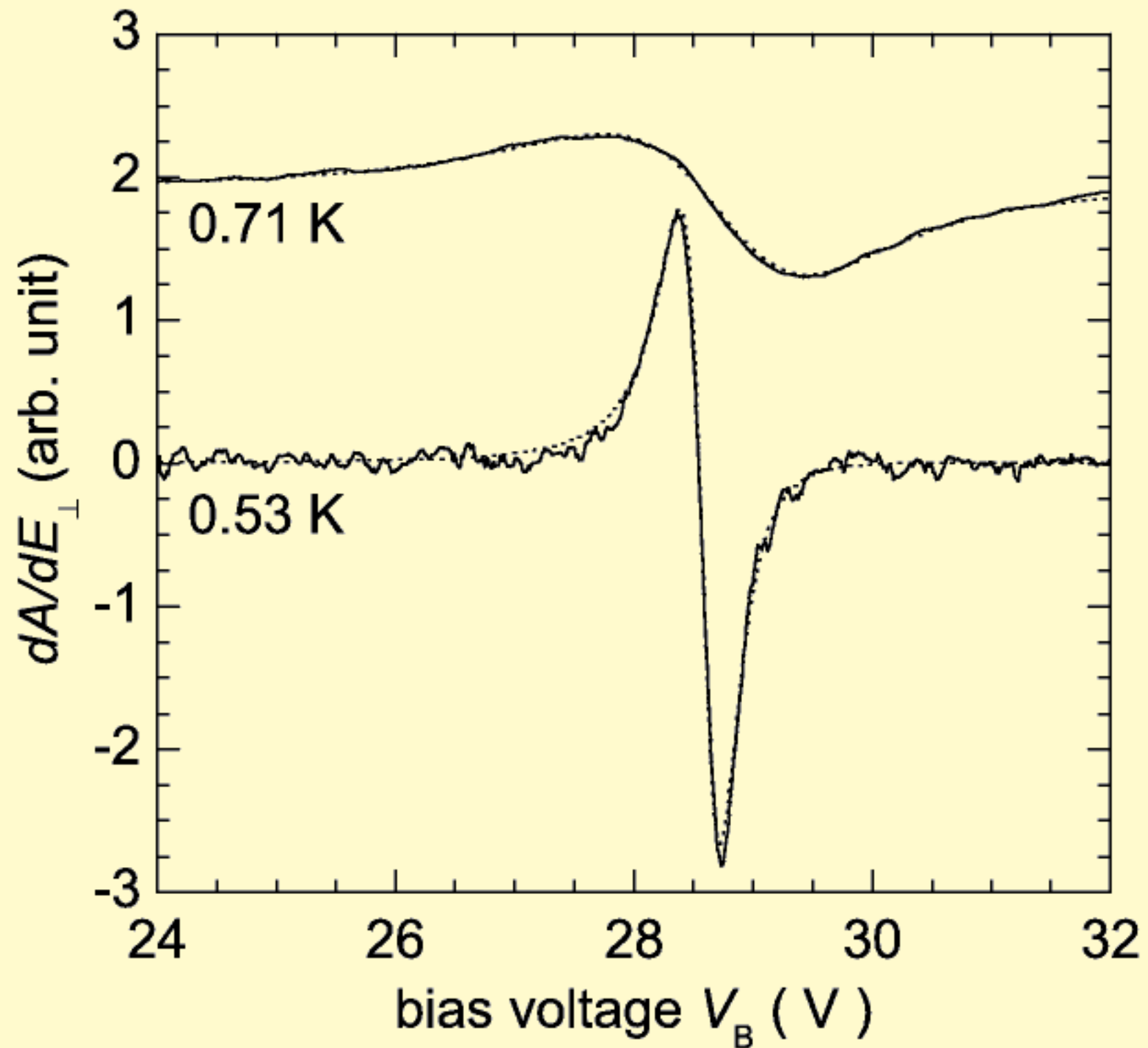
Experimental block diagram

C. C. Grimes and T. R. Brown: Phys. Rev. Lett. 32 (1974) 280.

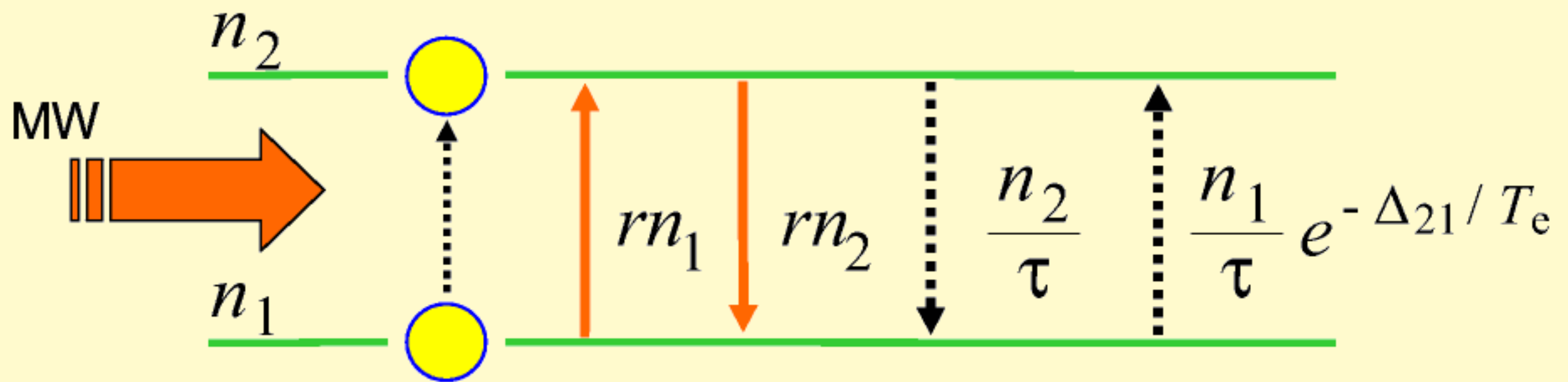
E. Collin et al.: Phys. Rev. Lett. 89 (2002) 245301.



Absorption signal



MW Absorption dynamics



Rate equation

$$\frac{dn_2}{dt} = r(n_1 - n_2) - \frac{1}{\tau}(n_2 - n_1 e^{-\Delta_{21}/T_e})$$

$$n_1 + n_2 = 1$$

$$\Delta_{mn} = \epsilon_m - \epsilon_n$$

r : Stimulated absorption (emission) rate

τ : Relaxation time

Absorption rate

$$r = \frac{1}{2} \frac{\Omega_R^2 \gamma}{\delta^2 + \gamma^2}$$

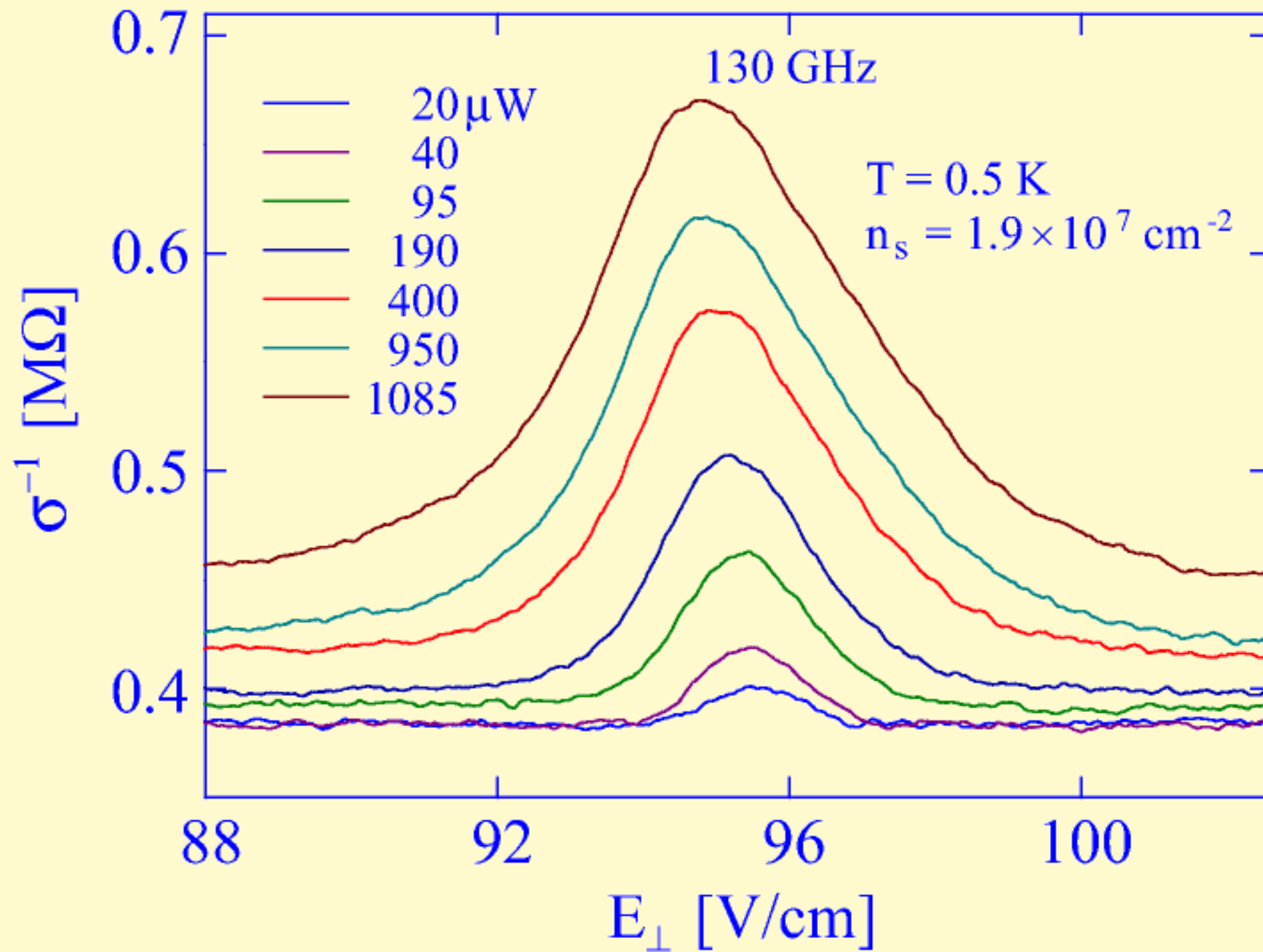
$$\delta = \omega_0 - \omega, \quad \hbar\omega_0 = \Delta_{21}$$

γ Linewidth

$$\hbar\Omega_R = eE_0 \langle 1|z|2 \rangle \quad (\text{Rabi frequency})$$

E_0 Microwave electric field

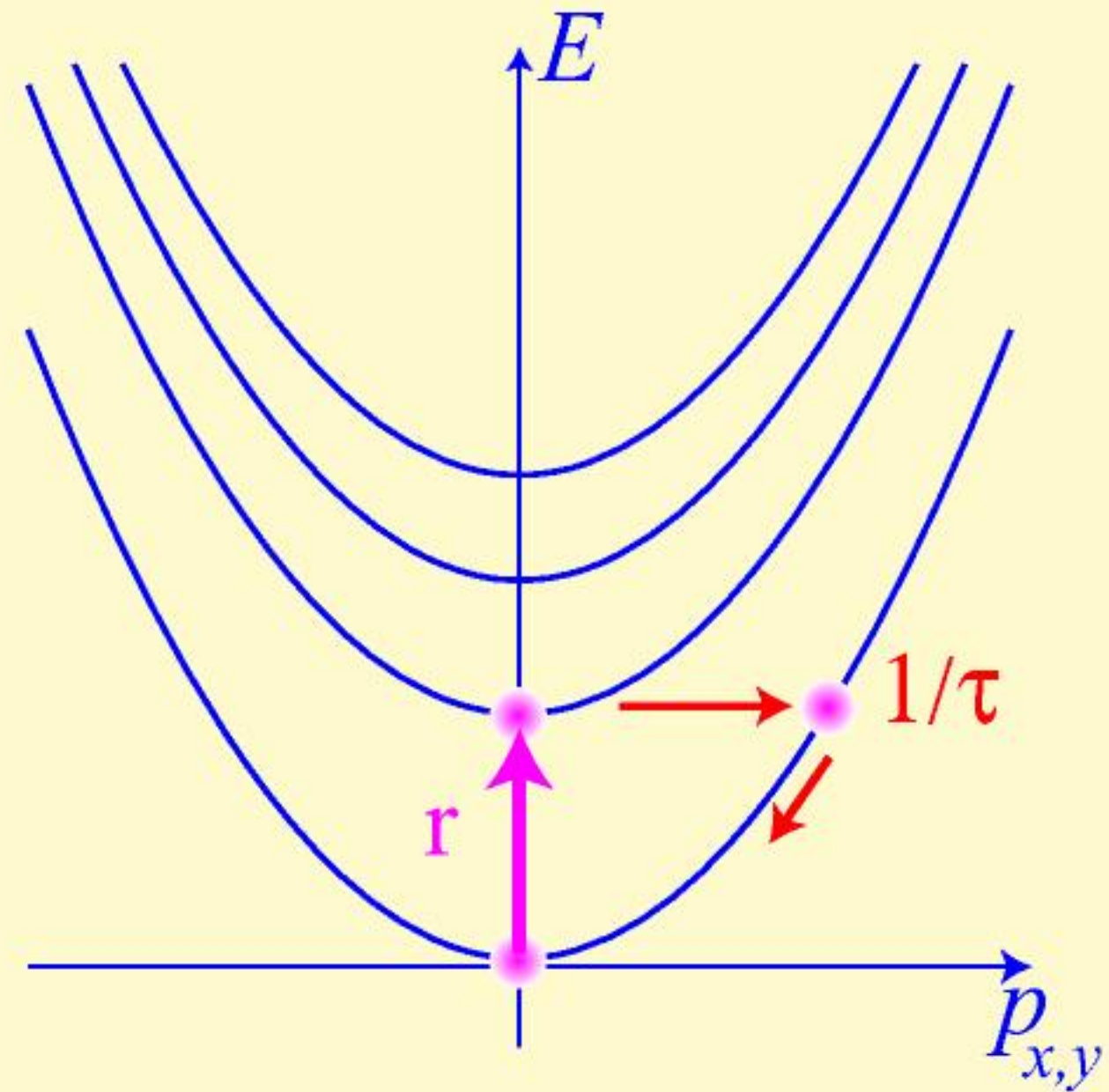
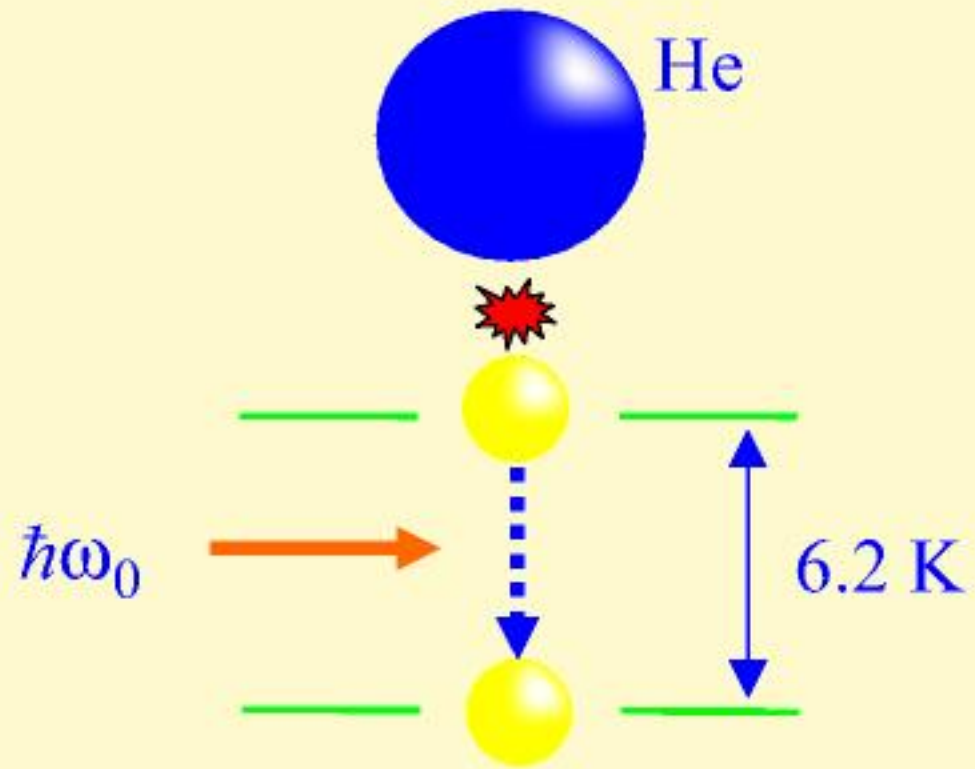
MW induced resistivity



Relaxation dynamics

Total energy

$$E_n = \epsilon_n + \frac{p_{\parallel}^2}{2m}$$



To calculate T_e

Rate equation:

$$r (n_1 - n_2) = \frac{1}{\tau} (n_2 - n_1 e^{-\Delta_{21}/T_e})$$

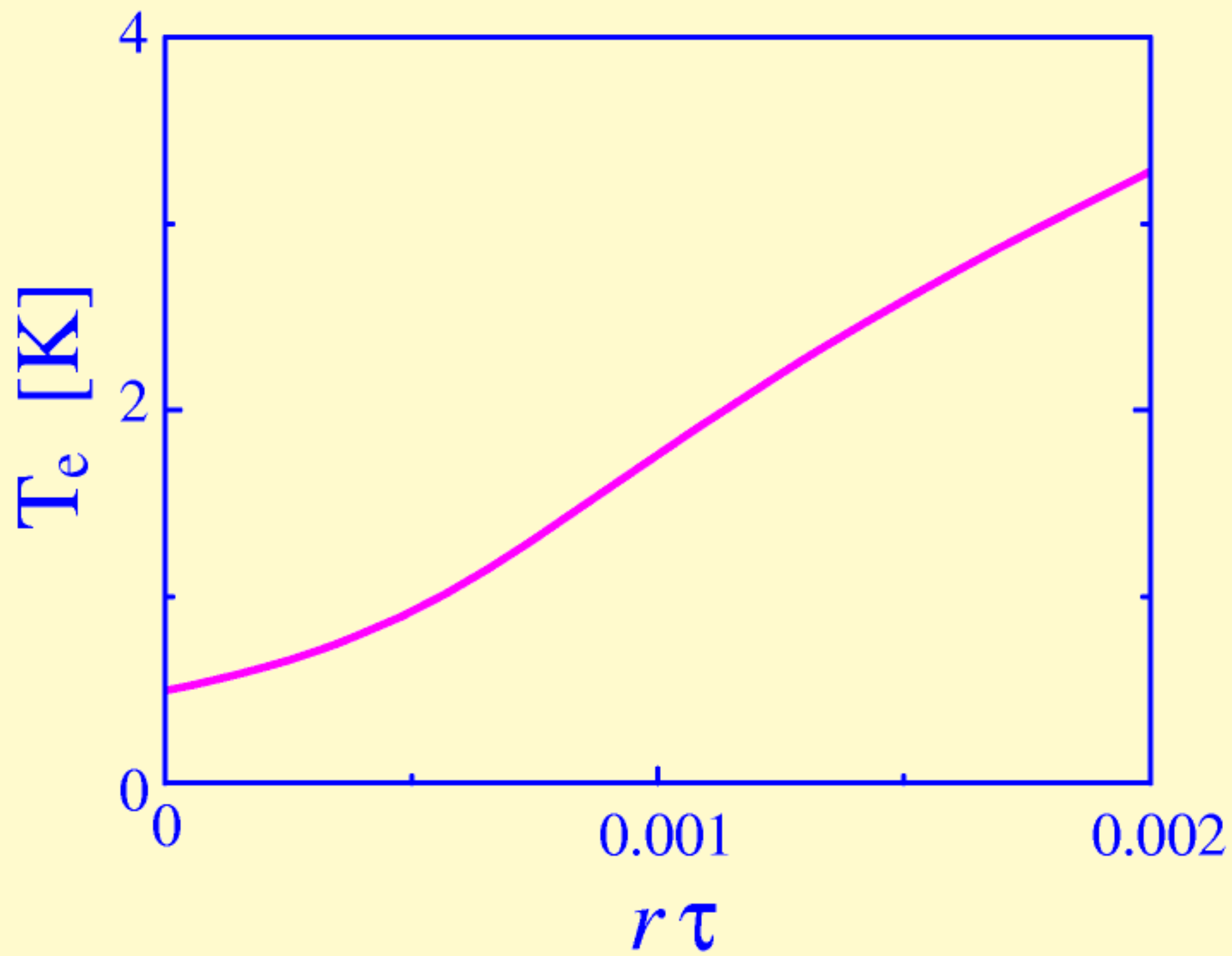
$$n_i = Z^{-1} e^{-\frac{\Delta_{i1}}{T_e}} \quad (i \geq 3), \quad Z = \sum_{i=1}^{\infty} e^{-\frac{\Delta_{i1}}{T_e}}$$

Energy balance equation:

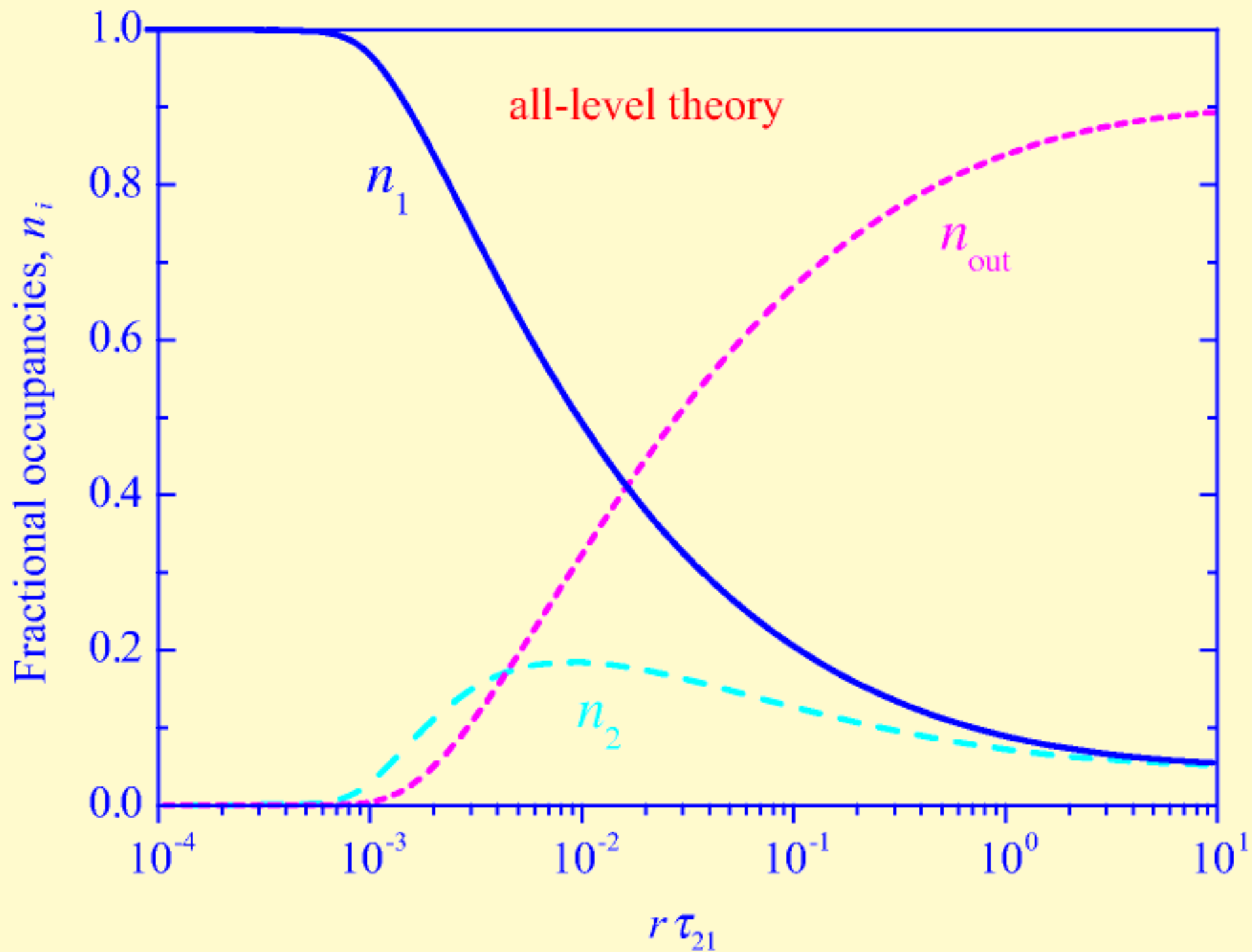
$$(T_e - T) \nu_E(T_e) = \hbar\omega r (n_1 - n_2)$$

$$\nu_E(T_e) \approx \frac{m}{M} \frac{1}{\tau}$$

T_e



Fractional occupancy



Mobility vs. T_e

$$\mu = \frac{e}{m\nu_M}$$

$$\nu_M(T_e) = \nu_M^0 \sum_{ij} s_{ij} n_j e^{-(|\Delta_{ij}| + \Delta_{ij})/2T_e} \left[1 + \frac{|\Delta_{ij}| + \Delta_{ij}}{2T_e} \right]$$

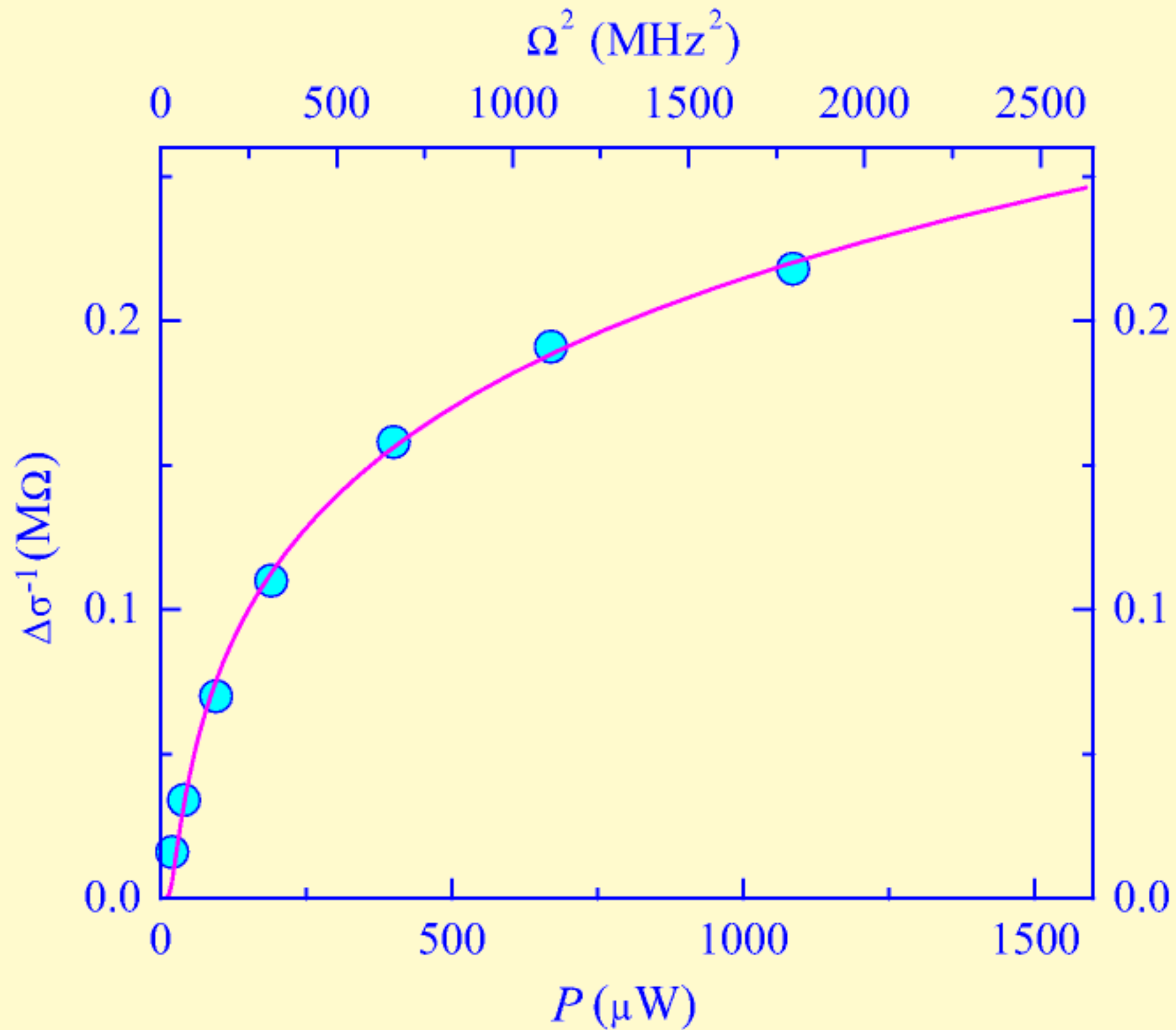
$$s_{ij} = \frac{\int_0^\infty dz [\psi_i(z)\psi_j(z)]^2}{\int_0^\infty dz \psi_1(z)^4}$$

$$\Delta_{ij} = \epsilon_i - \epsilon_j$$

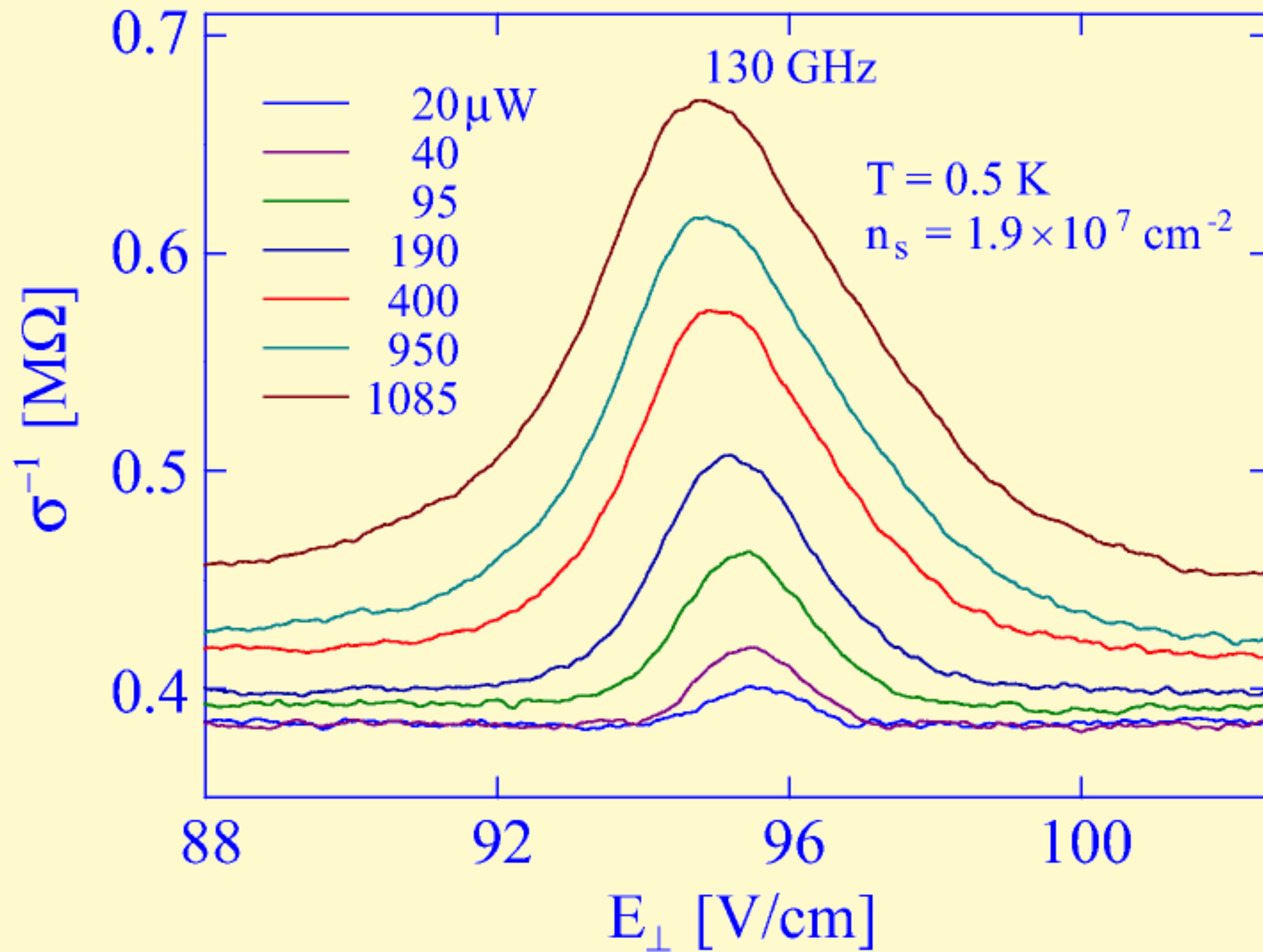
M. Saitoh and T. Aoki: J. Phys. Soc. Jpn 44 (1977) 71.

Yu. P. Monarkha et al.: J. Phys. Soc. Jpn 76 (2007) 124702.

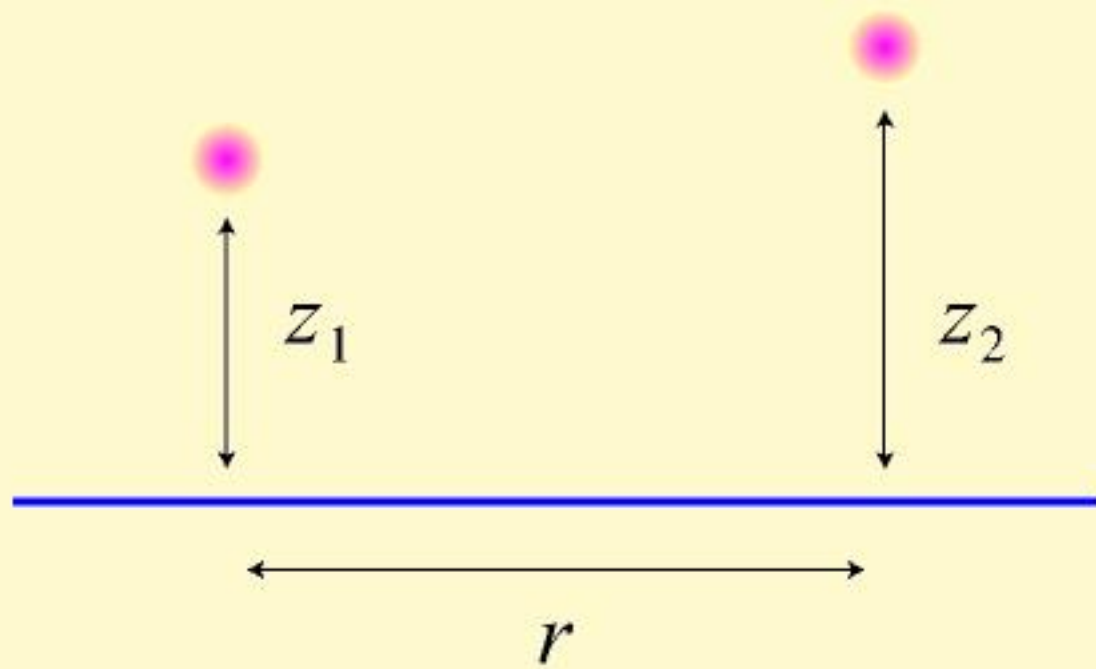
Resistance peak height



Resonance frequency shift



Coulomb interaction



$$V(z_1, z_2) \approx \frac{e^2}{r} \left(1 - \frac{(z_1 - z_2)^2}{2r^2} \right)$$

$$H_I = -\frac{e^2}{2r^3} (z_1 - z_2)^2$$

A correction to Δ_{21} from the neighboring electron in the l th-state

$$\Delta E \approx \langle 2 | \langle l | H_I | l \rangle | 2 \rangle - \langle 1 | \langle l | H_I | l \rangle | 1 \rangle$$

$$= -\frac{e^2}{2r^3} \left[\langle 2 | z^2 | 2 \rangle - \langle 1 | z^2 | 1 \rangle - 2 \left(\langle 2 | z | 2 \rangle - \langle 1 | z | 1 \rangle \right) \langle l | z | l \rangle \right]$$

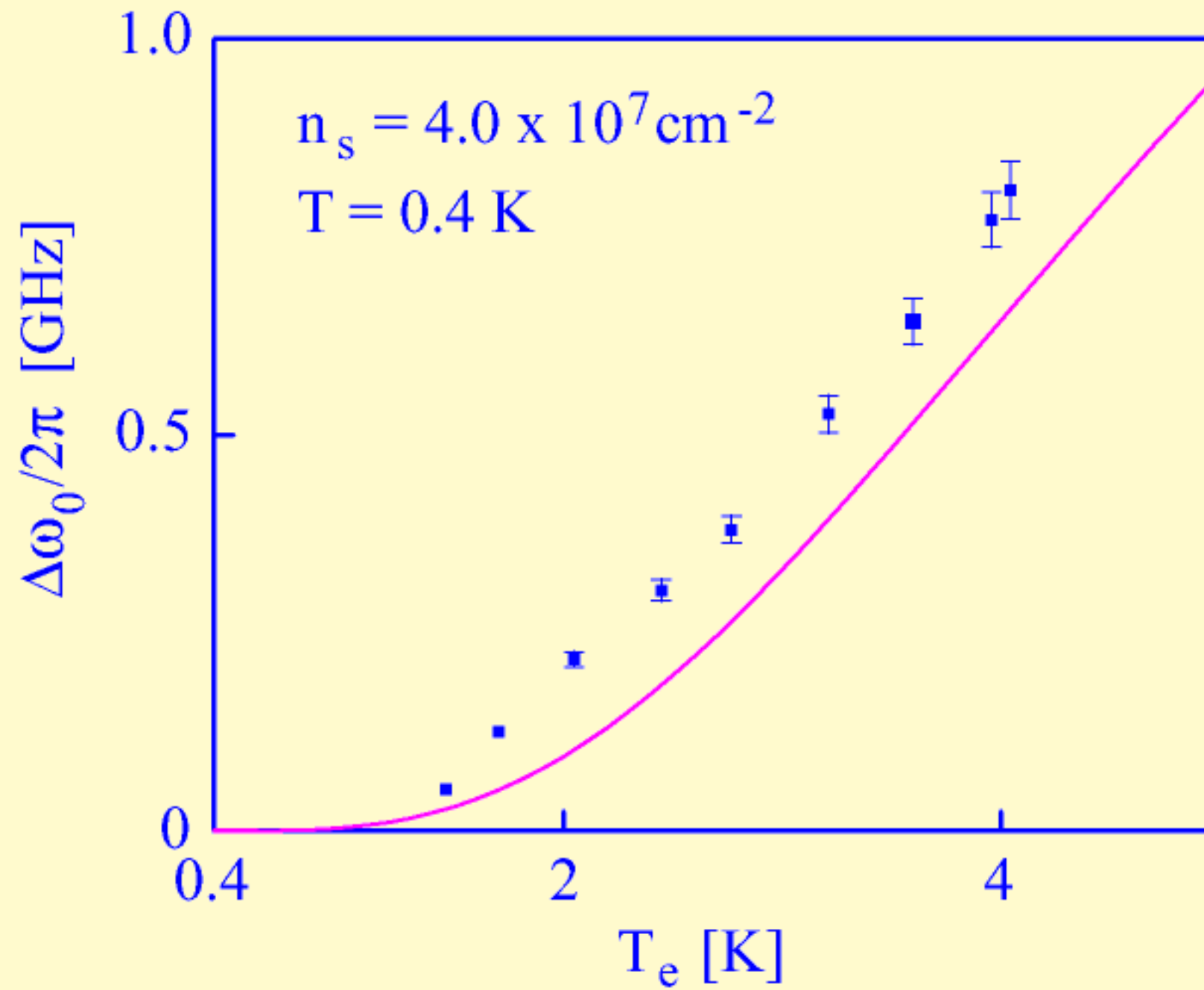
MW power dependent shift:

$$\Delta\omega_0 = \frac{F e^2 n_s^{3/2}}{\hbar} \left(\langle 2|z|2\rangle - \langle 1|z|1\rangle \right) \left(\sum_l \langle l|z|l\rangle n_l - \langle 1|z|1\rangle \right)$$

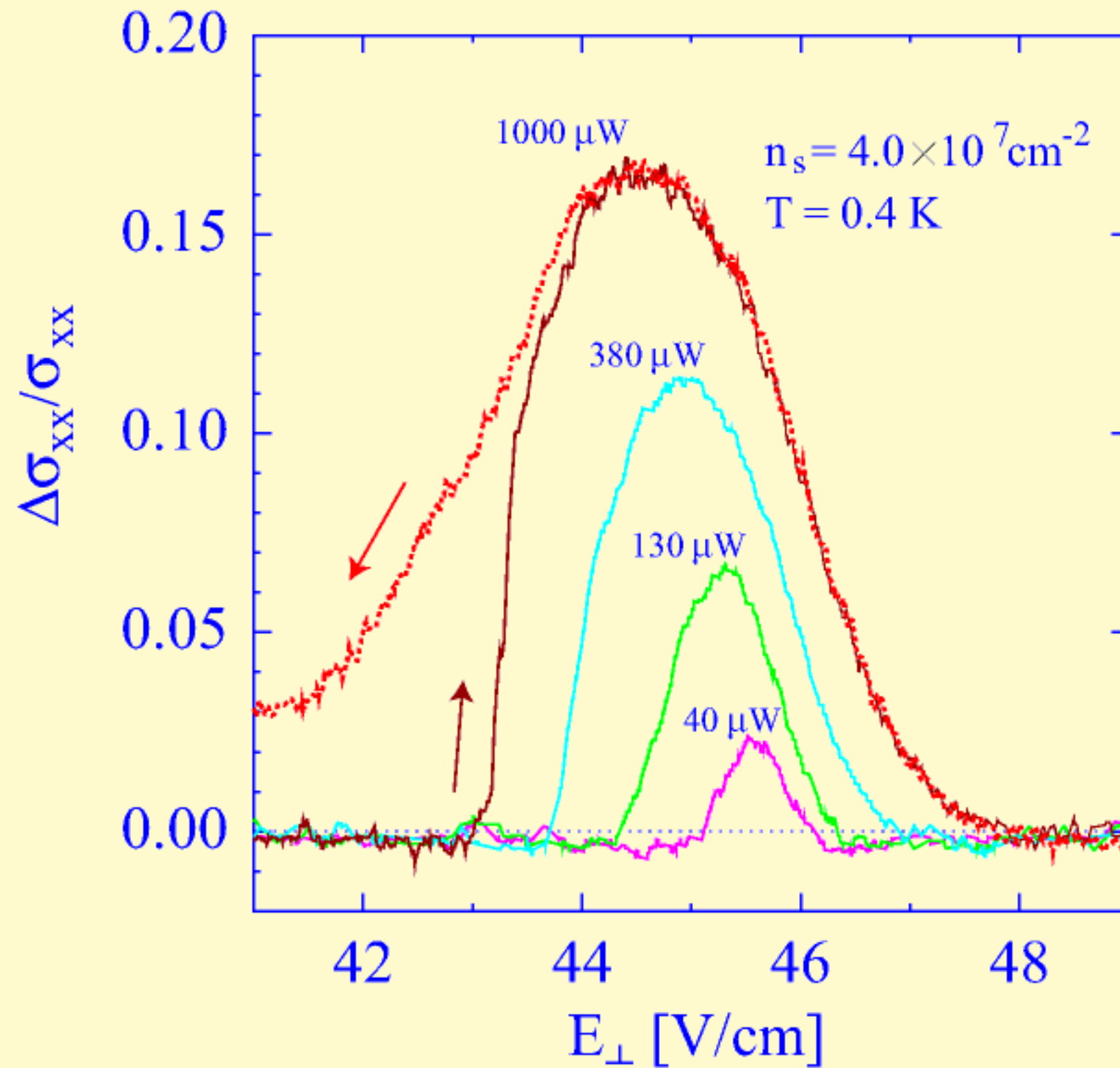
$$F = \frac{1}{\sqrt{n_s}} \int_0^\infty \frac{g(r)}{r^3} 2\pi r dr$$

≈ 8.91 for triangular lattice

Shift of resonance frequency



Hysteresis



Paris in 2006

HYSTERESIS AND BLEACHING OF ABSORPTION BY ELECTRONS ON HELIUM

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¹ Department of Physics and Astronomy, Michigan State University

² Royal Holloway, University of London

- Dynamics for slow energy relaxation
- Absorption bleaching
- Many-electron hysteresis



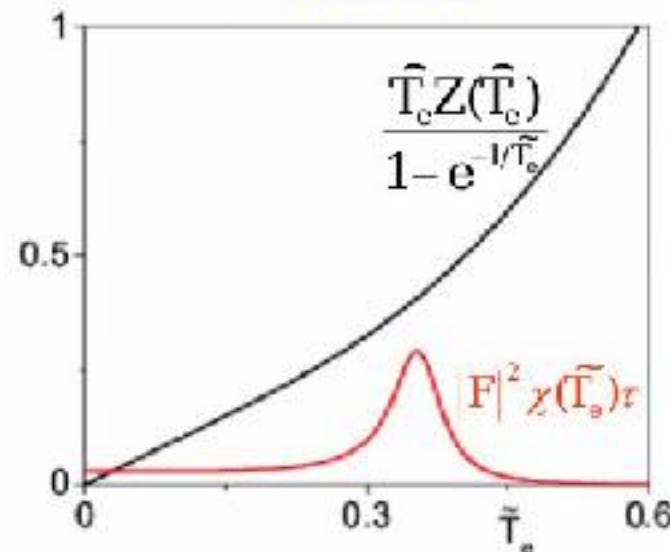
Self-consistent equation for ee temperature

$$\frac{\hat{T}_c Z(\hat{T}_c)}{1 - e^{-1/\hat{T}_c}} = |F|^2 \chi(\tilde{T}_e) \tau, \quad \tilde{T}_e = \frac{T_c}{\omega_\Gamma}$$

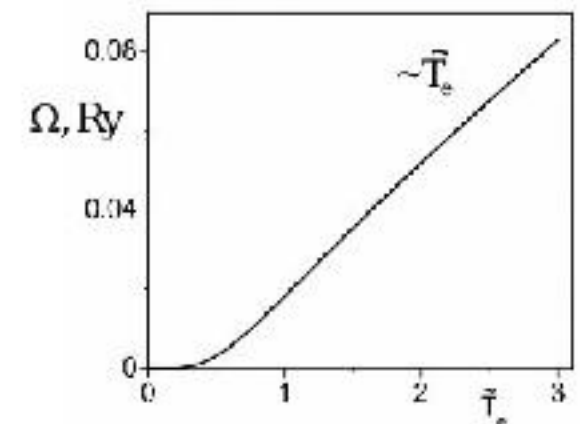
$\chi(\tilde{T}_e)$ has a narrow peak for $\delta\omega = \Omega(\tilde{T}_e^*)$ if $[d\Omega/d\tilde{T}_e]_{\tilde{T}_e^*} \gg \Gamma_0$

Constant energy relaxation rate approximation

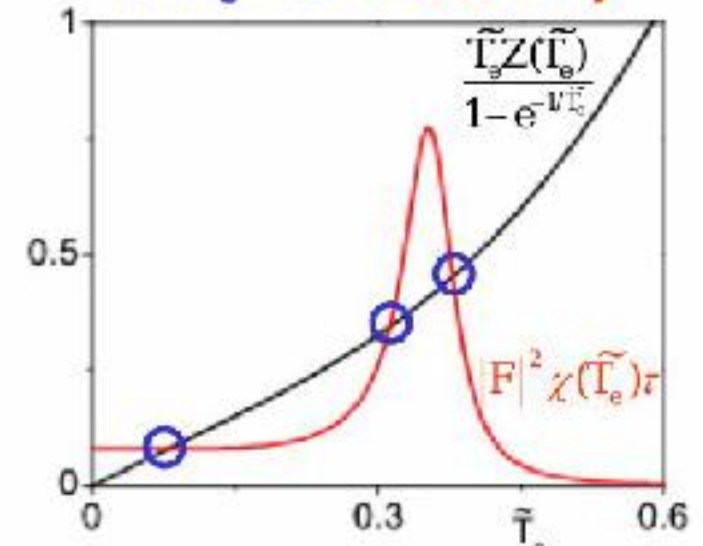
weak field



Many-electron bistability

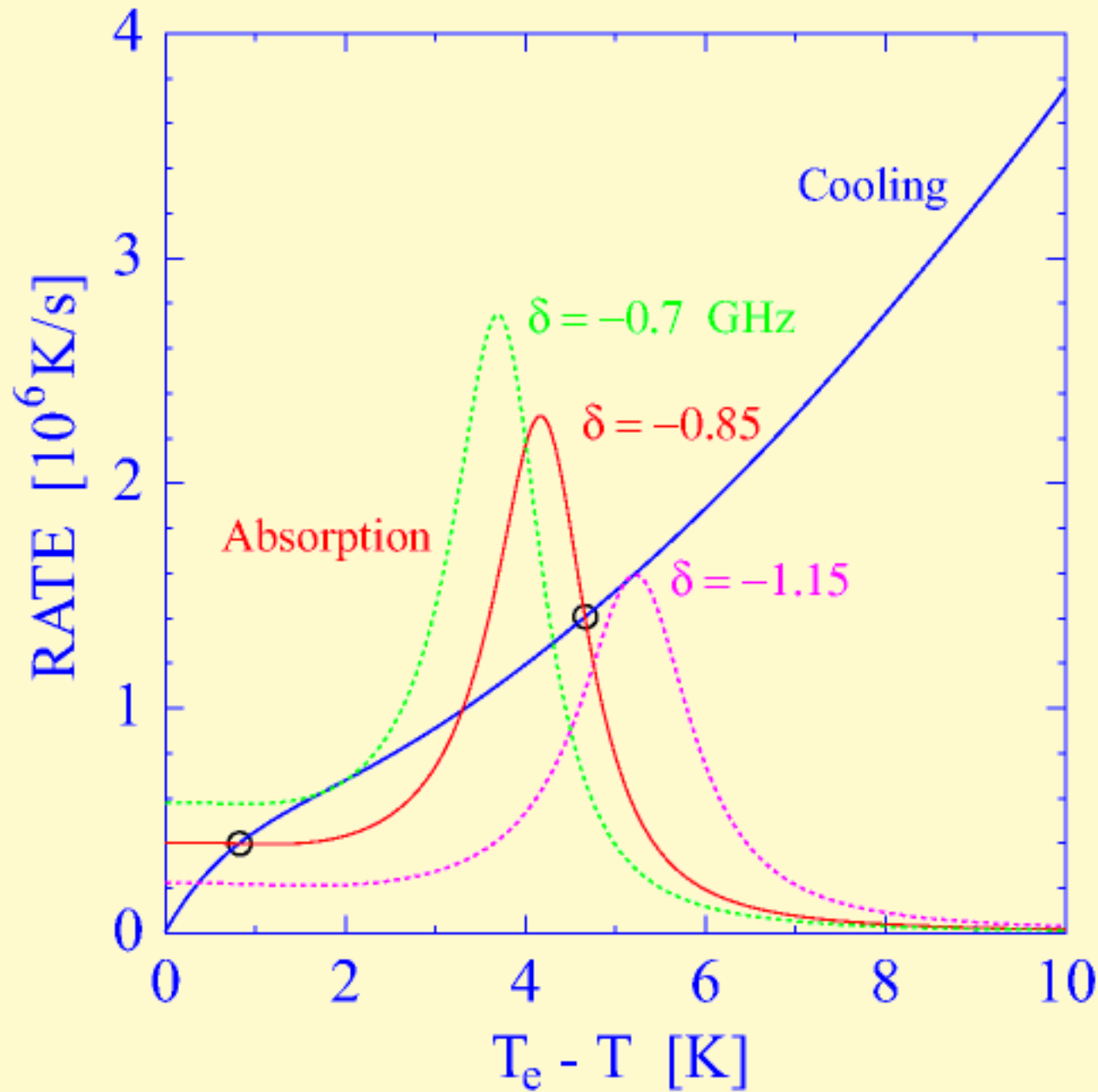


strong field → bistability



$$\delta\omega/\Gamma_0 = 1, \delta\omega = 0.001\text{Ry}$$

Energy balance and bistability

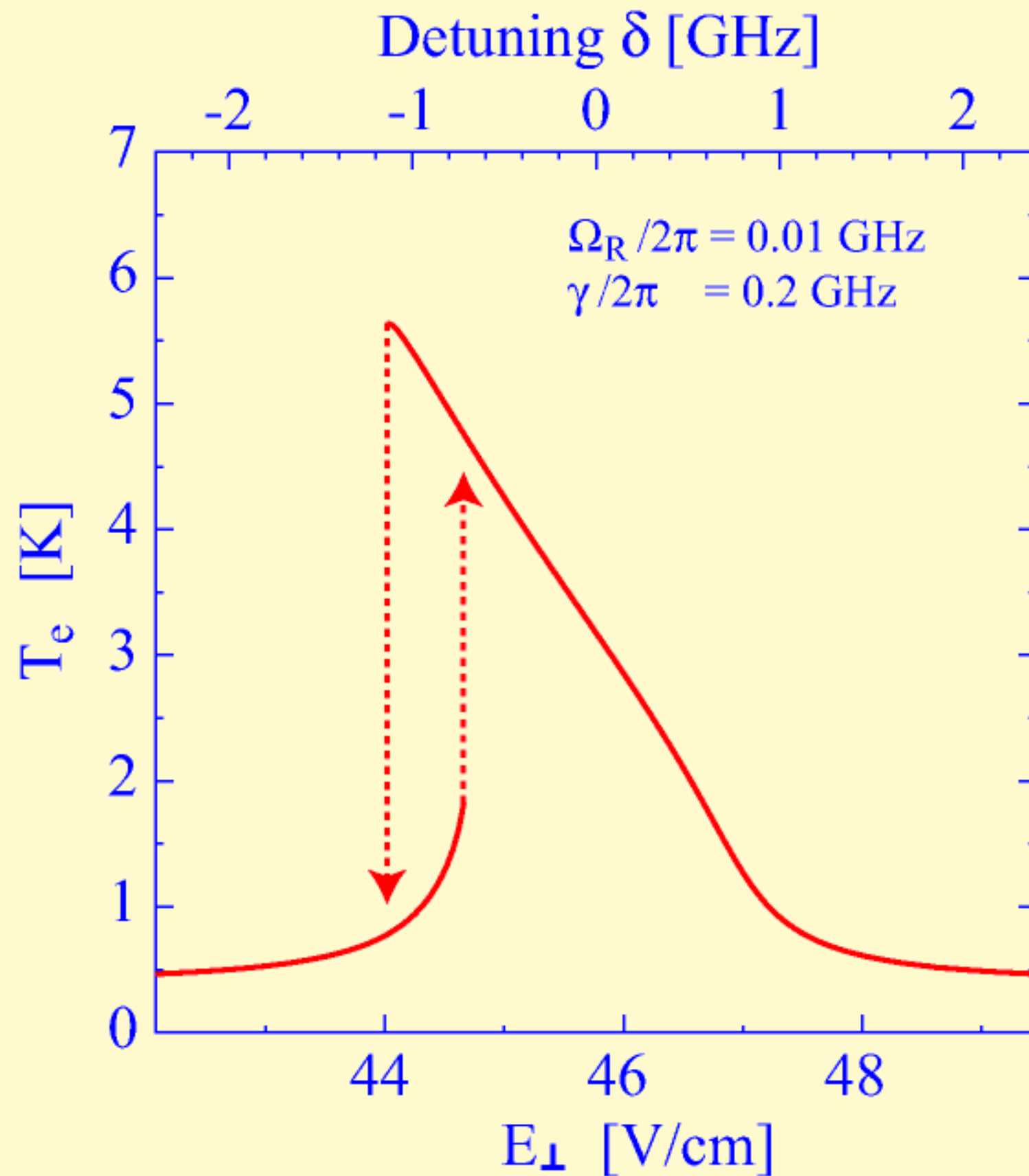


$$r = \frac{1}{2} \frac{\Omega_R^2 \gamma}{(\delta + \Delta\omega_0(T_e))^2 + \gamma^2}$$

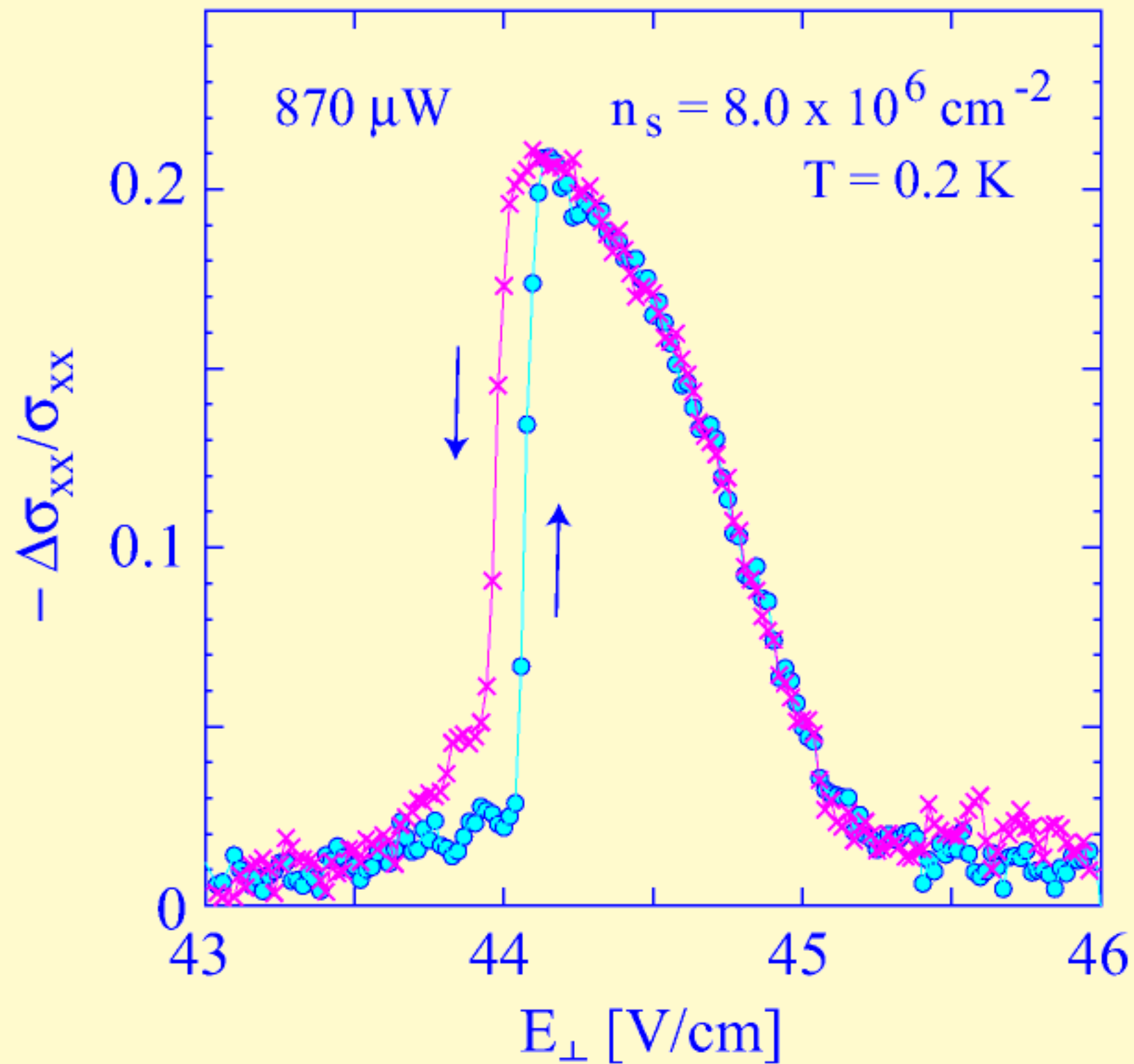
$$\delta = \omega_0 - \omega$$

$$\hbar\omega r(n_1 - n_2) = \nu_E(T_e)(T_e - T)$$

Hysteresis (model)



Hysteresis (0.2K)



Wako in 2008

Temperature Instability and Intersubband
Absorption Hysteresis
in Surface Electrons on ^3He

D. Konstantinov and K. Kono

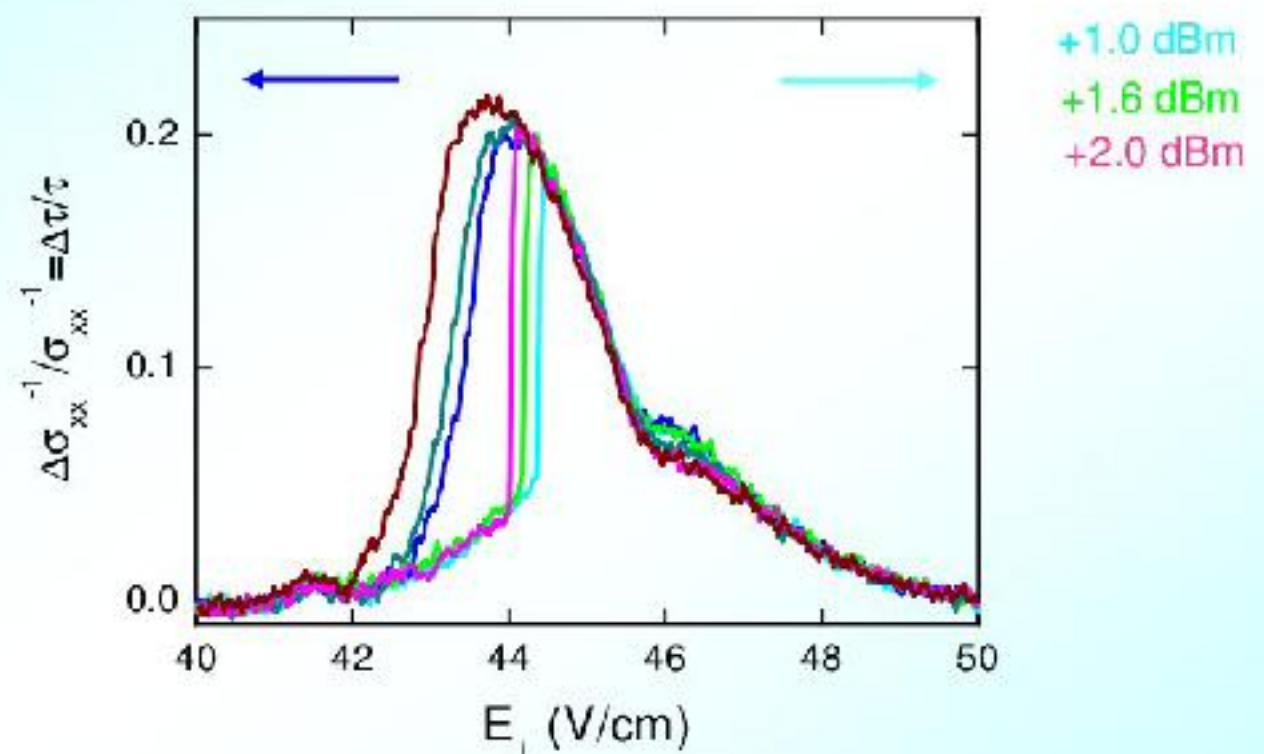


Low Temperature Physics Laboratory

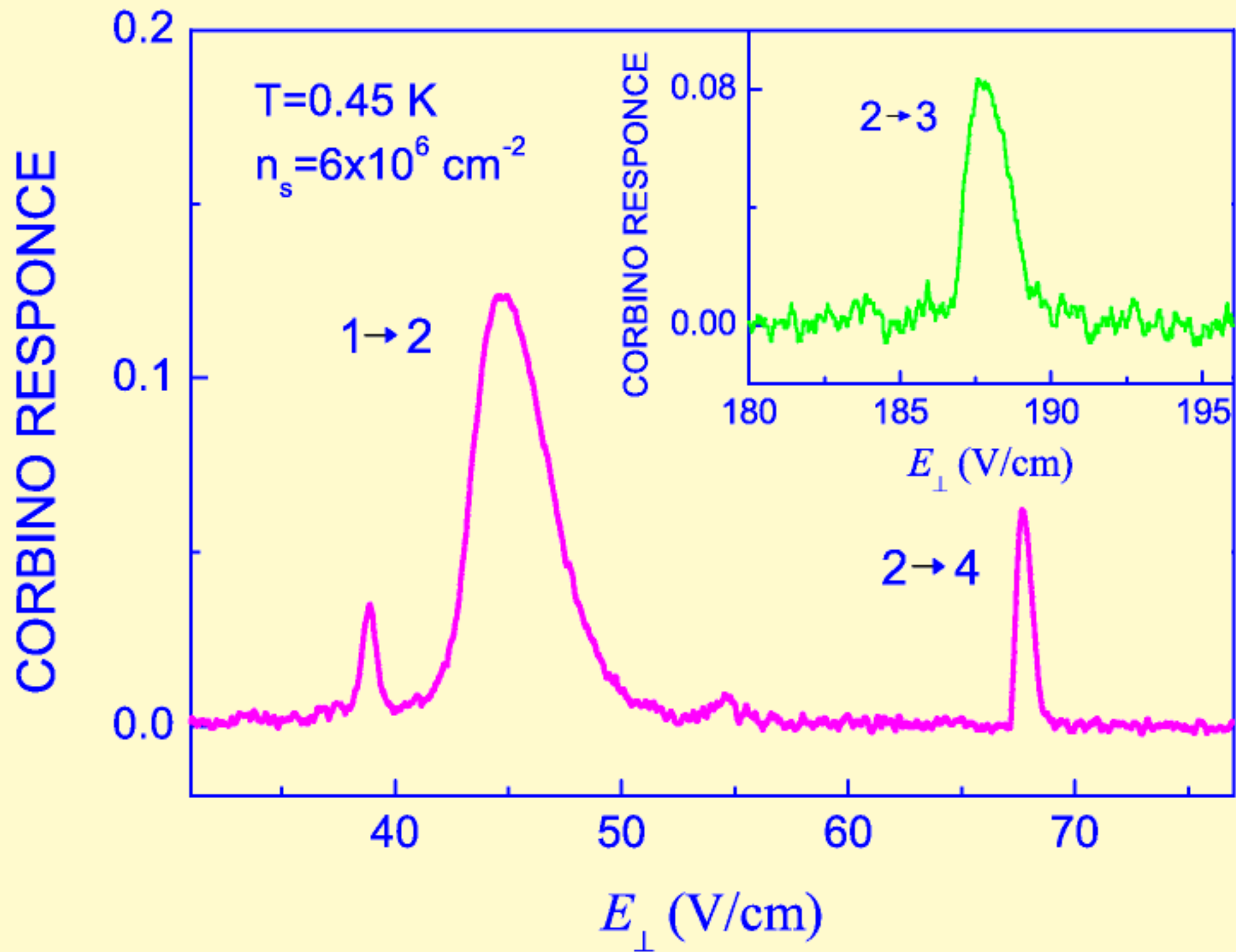
Instability

T=200 mK

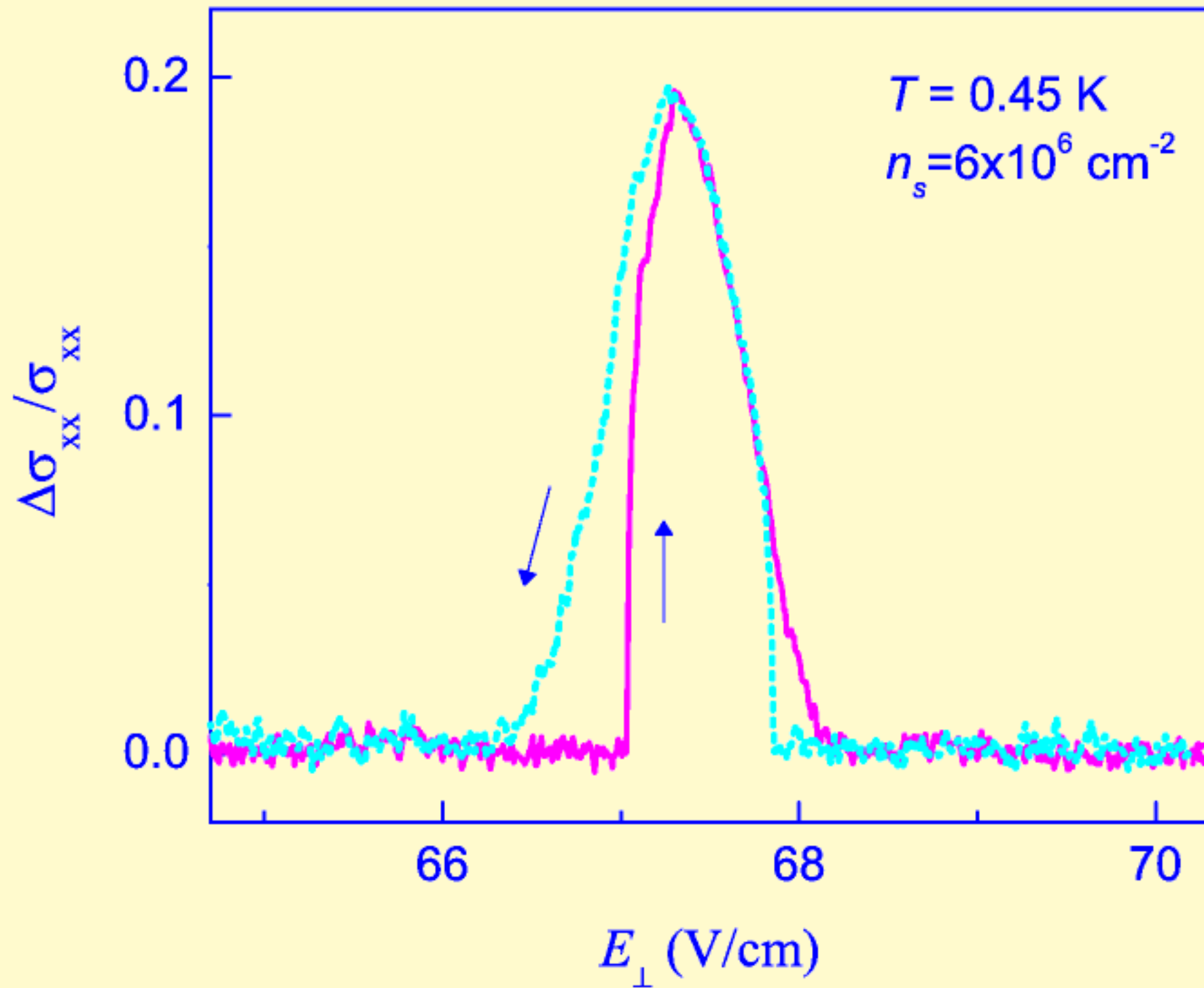
$n_e = 4.2 \times 10^7 \text{ cm}^{-2}$



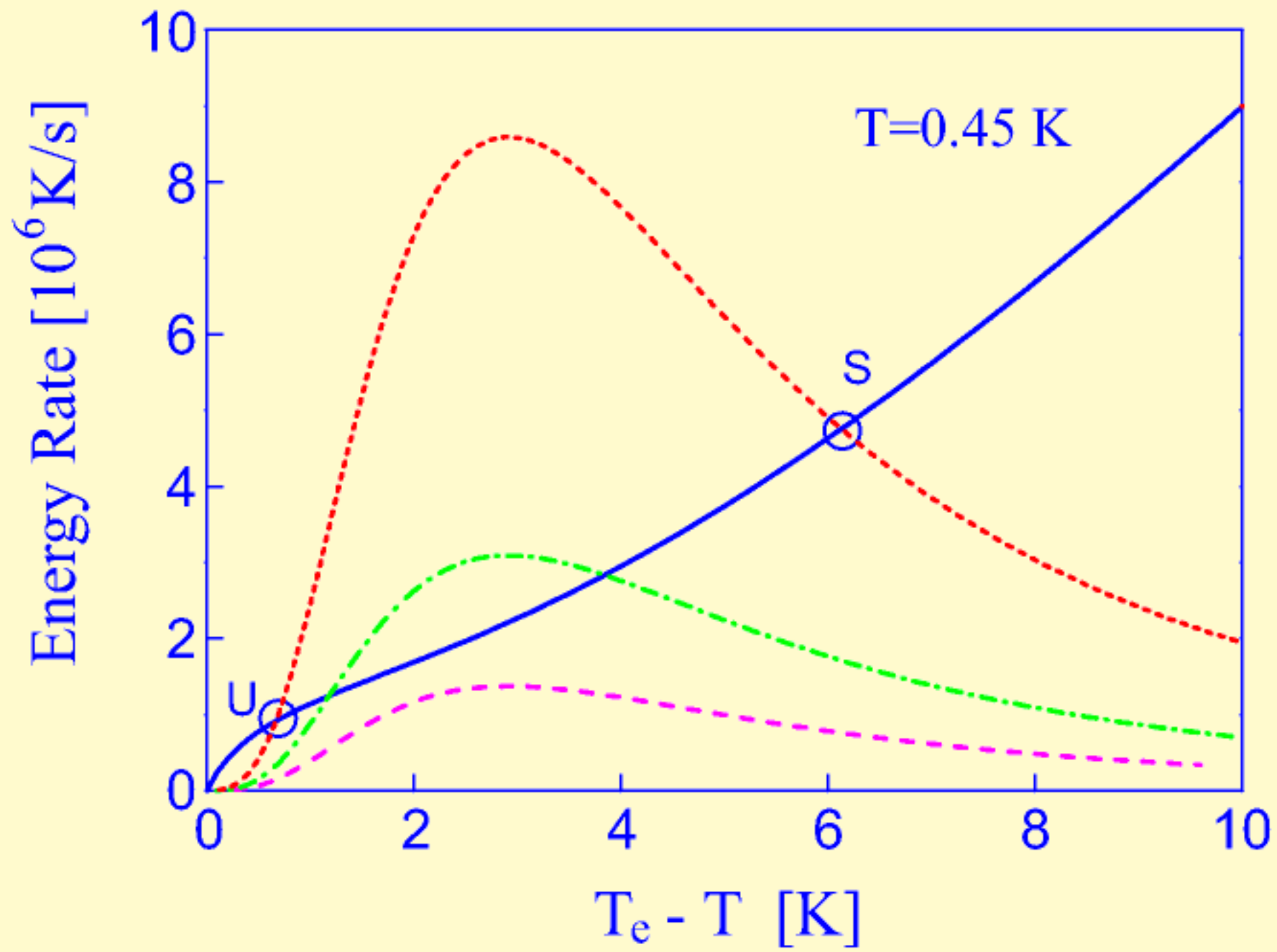
Self-sustained absorption



Hysteresis



Model



Conclusion

- Microwave-induced hot-electron effect is important
- Coulomb interaction causes a frequency shift
- Resonance line-shape shows hysteresis at high MW power
- The hysteresis is attributed to temperature bistability
- Self-sustained MW absorption is found
- This series of workshops is really productive